

# ESD Protection Diode

## Micro-Packaged Diodes for ESD Protection

### ESD9C3.3ST5G SERIES

The ESD9C3.3ST5G Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications.

#### Specification Features:

- Low Capacitance 6.2 pF – 13 pF
- Low Clamping Voltage
- Small Body Outline Dimensions:  
0.039" x 0.024" (1.0 mm x 0.60 mm)
- Low Body Height: 0.016" (0.40 mm) Max
- Stand-off Voltage: 3.3 V, 5 V
- Low Leakage
- Response Time < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

#### MAXIMUM RATINGS

| Rating   | Symbol                            | Value       | Unit |
|--|-----------------------------------|-------------|------|
| IEC 61000-4-2 (ESD) Contact Air  |                                   | ±8.0<br>±15 | kV   |
| Total Power Dissipation on FR-5 Board (Note 1) @ T <sub>A</sub> = 25°C | P <sub>D</sub>                    | 150         | mW   |
| Junction and Storage Temperature Range                                 | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C   |
| Lead Solder Temperature – Maximum (10 Second Duration)                 | T <sub>L</sub>                    | 260         | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 = 1.0 x 0.75 x 0.62 in.

See Application Note AND8308/D for further description of survivability specs.



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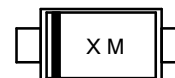


PIN 1. CATHODE  
2. ANODE



SOD-923  
CASE 514AB

#### MARKING DIAGRAM



X = Specific Device Code  
M = Date Code

#### ORDERING INFORMATION

| Device        | Package           | Shipping†        |
|---------------|-------------------|------------------|
| ESD9CxxST5G   | SOD-923 (Pb-Free) | 8000/Tape & Reel |
| SZESD9CxxST5G | SOD-923 (Pb-Free) | 8000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the table on page 2 of this data sheet.

# ESD9C3.3ST5G SERIES

## ELECTRICAL CHARACTERISTICS

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Symbol    | Parameter                                    |
|-----------|--|
| $I_{PP}$  | Maximum Reverse Peak Pulse Current           |
| $V_C$     | Clamping Voltage @ $I_{PP}$                  |
| $V_{RWM}$ | Working Peak Reverse Voltage                 |
| $I_R$     | Maximum Reverse Leakage Current @ $V_{RWM}$  |
| $V_{BR}$  | Breakdown Voltage @ $I_T$                    |
| $I_T$     | Test Current                                 |
| $I_F$     | Forward Current                              |
| $V_F$     | Forward Voltage @ $I_F$                      |
| $P_{pk}$  | Peak Power Dissipation                       |
| C         | Max. Capacitance @ $V_R = 0$ and $f = 1$ MHz |

\*See Application Note AND8308/D for detailed explanations of datasheet parameters.



## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 1.1$ V Max. @ $I_F = 10$ mA)

| Device       | Device Marking | $V_{RWM}$ (V) | $I_R$ ( $\mu\text{A}$ ) @ $V_{RWM}$ | $V_{BR}$ (V) @ $I_T$ (Note 2) | $I_T$ | C (pF) (Note 3) | C (pF) (Note 3) | $V_C$<br>Per IEC61000-4-2 (Note 4)       |
|--------------|----------------|---------------|-------------------------------------|-------------------------------|-------|-----------------|-----------------|--|
|              |                | Max           | Max                                 | Min                           | mA    | Typ             | Max             |  |
| ESD9C3.3ST5G | R              | 3.3           | 1.0                                 | 5.0                           | 1.0   | 12.8            | 13              | Figures 1 and 2<br>See Below<br>(Note 5) |
| ESD9C5.0ST5G | P              | 5.0           | 0.5                                 | 11.0                          | 1.0   | 6.0             | 6.2             |  |

- $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$ .
- Capacitance at  $f = 1$  MHz,  $V_R = 0$  V,  $T_A = 25^\circ\text{C}$ .
- For test procedure see Figures 3 and 4 and Application Note AND8307/D.
- ESD9C5.0ST5G shown below. Other voltages available upon request.

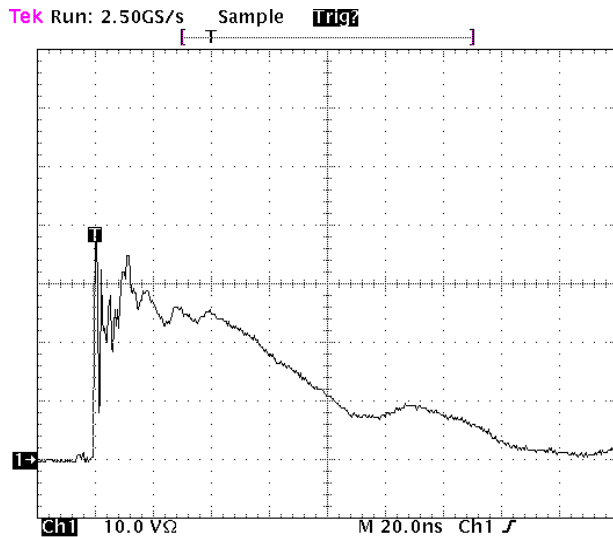


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000-4-2

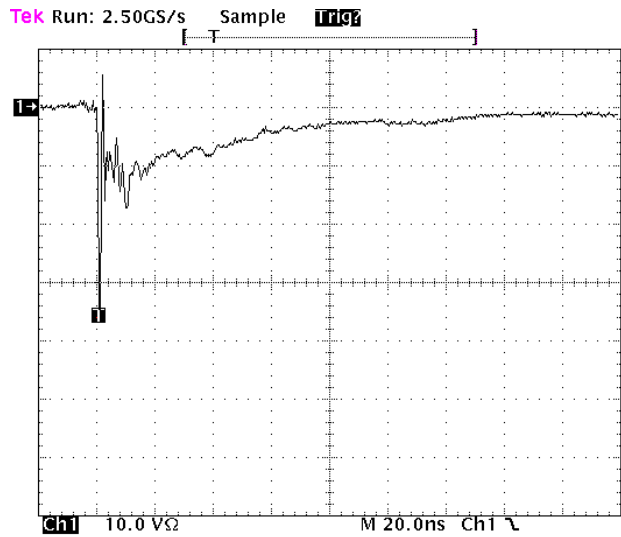


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2

# ESD9C3.3ST5G SERIES

## IEC 61000-4-2 Spec.

| Level | Test Voltage (kV) | First Peak Current (A) | Current at 30 ns (A) | Current at 60 ns (A) |
|-------|-------------------|------------------------|----------------------|----------------------|
| 1     | 2                 | 7.5                    | 4                    | 2                    |
| 2     | 4                 | 15                     | 8                    | 4                    |
| 3     | 6                 | 22.5                   | 12                   | 6                    |
| 4     | 8                 | 30                     | 16                   | 8                    |



Figure 3. IEC61000-4-2 Spec

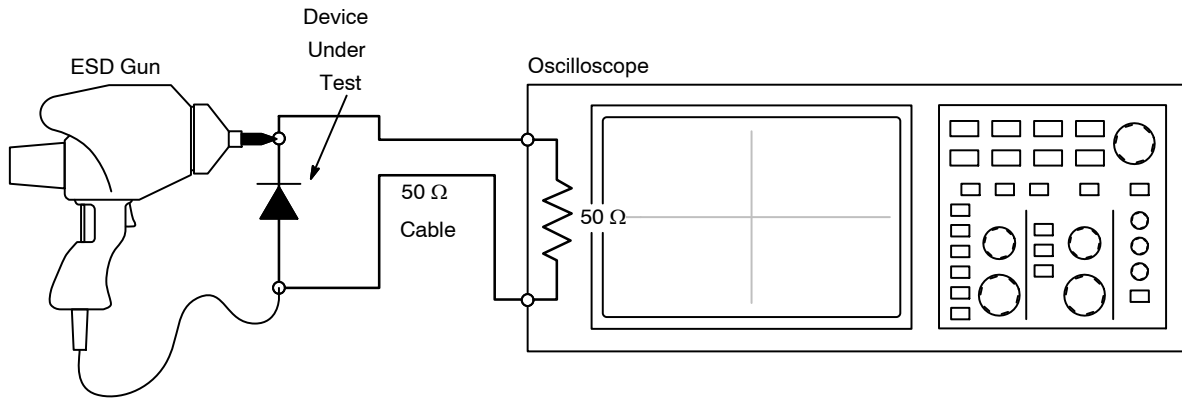


Figure 4. Diagram of ESD Test Setup

The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

### ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.



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